# **General Purpose Transistor**

## **NPN Silicon**

• Moisture Sensitivity Level: 1

• ESD Rating: Human Body Model: >4000 V

Machine Model: >400 V

 NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

• This is a Pb-Free Device

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit	
Collector-Emitter Voltage	V <sub>CEO</sub>	65	Vdc	
Collector-Base Voltage	V <sub>CBO</sub>	80	Vdc	
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	Vdc	
Collector Current – Continuous	Ic	100	mAdc	

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1)  T <sub>A</sub> = 25°C	$P_{D}$	265	mW
Derate above 25°C		2.1	mW/°C
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ hetaJA}$	470	°C/W
Total Device Dissipation Alumina Substrate (Note 2) T <sub>A</sub> = 25°C	$P_{D}$	640	mW
Derate above 25°C		5.1	mW/°C
Thermal Resistance, Junction to Ambient (Note 2)	$R_{\thetaJA}$	195	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

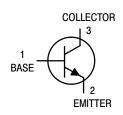
1

- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.



## ON Semiconductor®

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### MARKING DIAGRAM



SOT-723 CASE 631AA STYLE 1



1B = Specific Device Code M = Date Code

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BC846BM3T5G	SOT-723 (Pb-Free)	8000 / Tape & Reel
NSVBC846BM3T5G	SOT-723 (Pb-Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•		•	•	•
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA)	V <sub>(BR)</sub> CEO	65	-	_	V
Collector – Emitter Breakdown Voltage ( $I_C = 10 \mu A, V_{EB} = 0$ )	V <sub>(BR)</sub> CES	80	-	-	V
Collector – Base Breakdown Voltage ( $I_C = 10 \mu A$ )	V <sub>(BR)</sub> CBO	80	-	-	V
Emitter – Base Breakdown Voltage (I <sub>E</sub> = 1.0 μA)	V <sub>(BR)EBO</sub>	6.0	-	-	V
Collector Cutoff Current $(V_{CB} = 30 \text{ V})$ $(V_{CB} = 30 \text{ V}, T_A = 150^{\circ}\text{C})$	I <sub>CBO</sub>	-	- -	15 5.0	nA μA
ON CHARACTERISTICS					
DC Current Gain $ (I_C = 10 \ \mu\text{A, V}_{CE} = 5.0 \ \text{V}) $ $ (I_C = 2.0 \ \text{mA, V}_{CE} = 5.0 \ \text{V}) $	h <sub>FE</sub>	_ 200	150 290	- 450	_
Collector – Emitter Saturation Voltage ( $I_C$ = 10 mA, $I_B$ = 0.5 mA) ( $I_C$ = 100 mA, $I_B$ = 5.0 mA)	V <sub>CE(sat)</sub>		_ _	0.25 0.6	V
Base – Emitter Saturation Voltage ( $I_C$ = 10 mA, $I_B$ = 0.5 mA) ( $I_C$ = 100 mA, $I_B$ = 5.0 mA)	V <sub>BE(sat)</sub>	-	0.7 0.9	- -	V
Base – Emitter Voltage (I <sub>C</sub> = 1.0 mA, V <sub>CE</sub> = 5.0 V) (I <sub>C</sub> = 2.0 mA, V <sub>CE</sub> = 5.0 V) (I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 5.0 V)	V <sub>BE(on)</sub>	550 580 -	645 660 –	700 700 770	mV
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product (I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 5.0 Vdc, f = 100 MHz)	f <sub>T</sub>	100	-	-	MHz
Output Capacitance (V <sub>CB</sub> = 10 V, f = 1.0 MHz)	C <sub>obo</sub>	-	-	4.5	pF
Noise Figure (I <sub>C</sub> = 0.2 mA, V <sub>CE</sub> = 5.0 Vdc, R <sub>S</sub> = 2.0 k $\Omega$ , f = 1.0 kHz, BW = 200 Hz)	NF	_	-	10	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

### **TYPICAL CHARACTERISTICS**

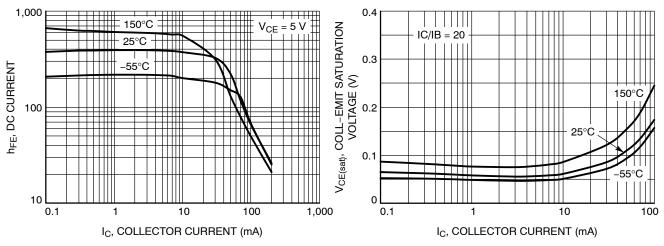


Figure 1. DC Current Gain

Figure 2. Collector-Emitter Saturation Voltage

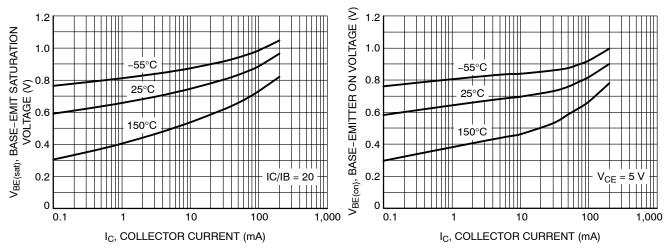


Figure 3. Base-Emitter Saturation Voltage

-0.2

-0.6

-1.0

-1.4

-1.8

-2.2

-2.6

0.1

= 5 V

 $\theta_{\mbox{\scriptsize VB}},$  for  $\mbox{\scriptsize V}_{\mbox{\scriptsize BE}}$ 

θ<sub>VB</sub>, TEMPERATURE COEFFICIENT (mV)

V<sub>CE</sub>, COLLECTOR-EMITTER VOLTAGE (V) 2.0 = 25°C Î HIIII I<sub>C</sub> = 200 mA 10 mA 20 mA 50 mA 100 mA 1.6 1.2 8.0 0.4 1,000 0.01 0.1 10 100 IB, BASE CURRENT (mA)

Figure 4. Base-Emitter "On" Voltage

I<sub>C</sub>, COLLECTOR CURRENT (mA)

Figure 5. Base-Emitter Temperature

Coefficient

10

-55°C to 150°C

100

Figure 6. Collector Saturation Region

## **TYPICAL CHARACTERISTICS**

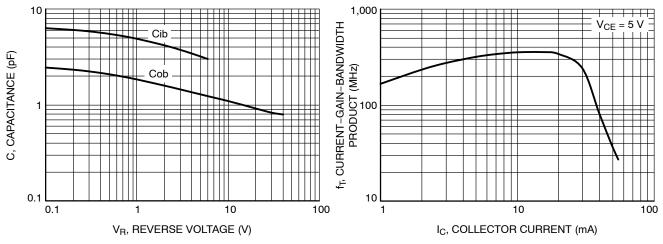


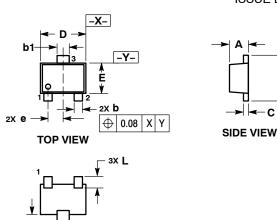
Figure 7. Capacitances

Figure 8. Current-Gain-Bandwidth Product

#### PACKAGE DIMENSIONS

#### SOT-723 CASE 631AA ISSUE D

 $H_{\mathsf{E}}$ 



**BOTTOM VIEW** 

#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS

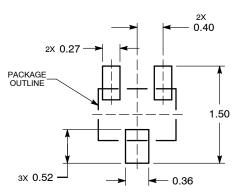
	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.45	0.50	0.55	
b	0.15	0.21	0.27	
b1	0.25	0.31	0.37	
С	0.07	0.12	0.17	
D	1.15	1.20	1.25	
E	0.75	0.80	0.85	
е	0.40 BSC			
ΗE	1.15	1.20	1.25	
L	0.29 REF			
L2	0.15	0.20	0.25	

STYLE 1:

PIN 1. BASE 2. EMITTER

3. COLLECTOR

### **RECOMMENDED SOLDERING FOOTPRINT\***



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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